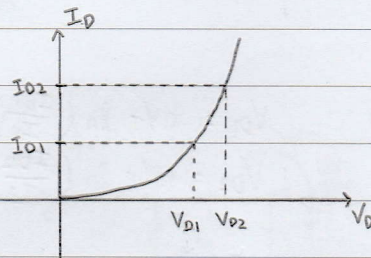


Esmund Lim

AE Tutorial 4

1a)



$$V_{D1} = nV_T \ln \frac{I_{D1}}{I_S} \quad \text{--- (1)}$$

$$V_{D2} = nV_T \ln \frac{I_{D2}}{I_S} \quad \text{--- (2)}$$

$$V_{D1} = 0.6V \quad I_{D1} = 2.3mA$$

$$V_{D2} = 0.8V \quad I_{D2} = 245mA$$

$$\begin{aligned} V_{D2} - V_{D1} &= nV_T \ln \frac{I_{D2}}{I_S} - nV_T \ln \left(\frac{I_{D1}}{I_S} \right) \\ &= nV_T \ln \left(\frac{I_{D2}}{I_S} \cdot \frac{I_S}{I_{D1}} \right) \\ &= nV_T \ln \left(\frac{I_{D2}}{I_{D1}} \right) \end{aligned}$$

$$\text{Note: } \ln \left(\frac{3}{2} \right) - \ln \left(\frac{2}{3} \right)$$

$$= \ln \left(\frac{3}{2} \cdot \frac{3}{2} \right)$$

$$= \ln \left(\frac{9}{4} \right)$$

$$\begin{aligned} nV_T &= \frac{V_{D2} - V_{D1}}{\ln \left(\frac{I_{D2}}{I_{D1}} \right)} \\ &= \frac{0.8V - 0.6V}{\ln \left(\frac{245mA}{2.3mA} \right)} \\ &= 0.04284169762V \end{aligned}$$

$$\approx 42.8mV$$

Sub nV_T into (1)

$$0.6 = 42.8mV \left[\ln \left(\frac{2.3mA}{I_S} \right) \right]$$

$$14.00504726 = \ln \left(\frac{2.3mA}{I_S} \right)$$

$$e^{14.00504726} = \frac{2.3mA}{I_S}$$

$$I_S = \frac{2.3mA}{e^{14.00504726}}$$

$$= 1.902887408 \times 10^{-9}A$$

$$\approx 1.90nA$$

 \therefore The empirical diode junction equation

$$V_D = nV_T \ln \frac{i_D}{I_S}$$

$$= (42.8mV) \ln \left(\frac{i_D}{1.90nA} \right) \quad \text{--- (1)}$$

$$i_D = I_S e^{\frac{V_D}{nV_T}}$$

$$= (1.90nA) e^{\frac{V_D}{42.8mV}} \quad \text{--- (2)}$$

b) For $I_D = 20mA$

$$V_D = (42.8mV) \ln \left(\frac{20mA}{1.90nA} \right)$$

$$= 0.6920498469V$$

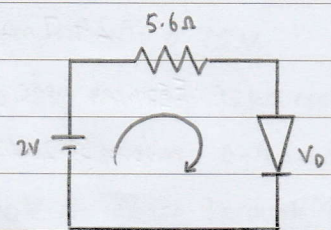
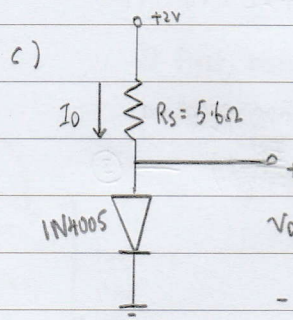
$$\approx 0.692V$$

For $I_D = 300mA$

$$V_D = (42.8mV) \ln \left(\frac{300mA}{1.90nA} \right)$$

$$= 0.8079543955V$$

$$\approx 0.808V$$



$$\begin{aligned} I_D &= \frac{V_S - V_D}{R} \\ &= \frac{2 - V_D}{5.6} \quad \text{--- (3)} \end{aligned}$$

By iteration method (DC)

	1st V_D value	obtained from (1)	Sub into (3)	
V_D	0.7V	0.797V	0.794V	0.794V
I_D	0.232A	0.215A	0.215A	0.215A

$$Q_{pt} (0.215A, 0.794V)$$

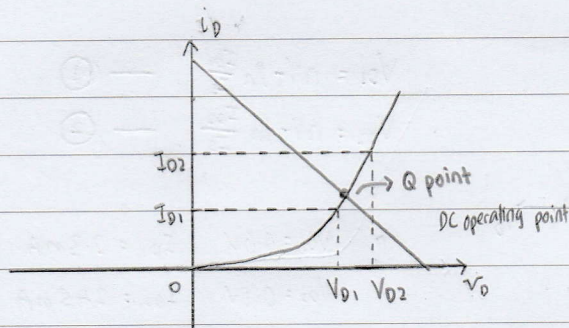
↑
obtained
from
eqn (3)

$$\therefore V_D = 0.794V$$

$$I_D = 0.215A$$

then Sub
into (1)

2)



$$V_{D1} = nV_T \ln \left(\frac{I_{D1}}{I_S} \right) \quad \text{--- ①}$$

$$V_{D2} = nV_T \ln \left(\frac{I_{D2}}{I_S} \right) \quad \text{--- ②}$$

$$V_{D1} = 0.50V \quad I_{D1} = 250\mu A$$

$$V_{D2} = 0.70V \quad I_{D2} = 10mA$$

$$V_{D2} - V_{D1} = nV_T \ln \left(\frac{I_{D2}}{I_S} \right) - nV_T \ln \left(\frac{I_{D1}}{I_S} \right)$$

$$= nV_T \ln \left(\frac{I_{D2}}{I_{D1}} \right)$$

$$= nV_T \ln \left(\frac{I_{D2}}{I_{D1}} \right)$$

$$nV_T = \frac{V_{D2} - V_{D1}}{\ln \left(\frac{I_{D2}}{I_{D1}} \right)}$$

$$= \frac{0.7 - 0.5}{\ln \left(\frac{10mA}{250\mu A} \right)}$$

$$= 0.05421700614V$$

$$\approx 54.2mV$$

Sub nV_T into ①

$$0.5 = 54.2mV \left(\ln \frac{250\mu A}{I_S} \right)$$

$$\frac{0.5}{54.2mV} = \ln \frac{250\mu A}{I_S}$$

$$I_S = \frac{250\mu A}{e^{\frac{0.5}{54.2mV}}}$$

$$= 24.70529422 \times 10^{-9} A$$

$$\approx 24.7nA$$

 \therefore Empirical diode junction equation

$$V_D = 54.2mV \left(\ln \frac{I_D}{24.7nA} \right) \quad \text{--- ③}$$

DC Analysis

 \rightarrow Remove the AC component

and just deal with DC component

$$g_d = \frac{I_D}{nV_T} \text{ (gradient of slope at Q-pt)}$$

$$= \frac{9.16mA}{54.2mV}$$

$$= 0.16900369$$

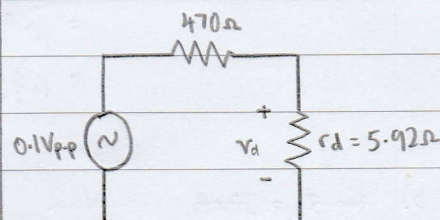
$$r_d = \frac{1}{g_d}$$

$$= \frac{1}{0.16900369}$$

$$= 5.917030568 \Omega$$

$$\approx 5.92 \Omega \quad \text{(AC diode resistance)}$$

AC Analysis

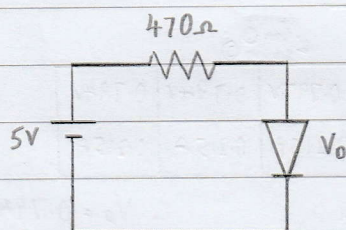
 \rightarrow Remove DC component

$$V_d = \frac{r_d}{r_d + R_s} V_s$$

$$= \frac{5.92}{5.92 + 470} (0.1)$$

$$= 1.243906539 \times 10^{-3} V_{p-p}$$

$$\approx 1.24 mV_{p-p}$$



Load line equation

$$I_D = \frac{V_S - V_D}{R}$$

$$= \frac{5 - V_D}{470\Omega} \quad \text{--- ④}$$

iteration method

V_D	0.7V	0.695V	0.695V
I_D	9.15mA	9.16mA	9.16mA

Q-pt (9.16mA, 0.695V)

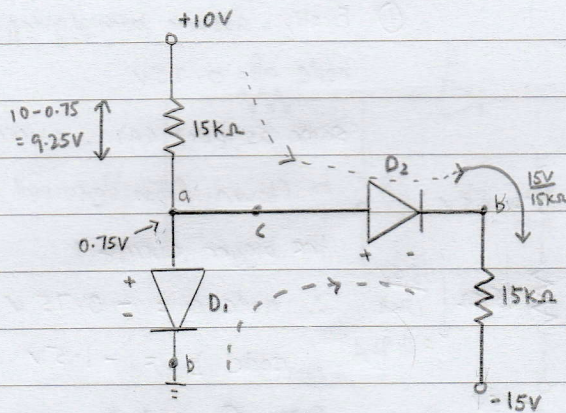
$$\therefore V_D = V_D + V_d \quad \text{peak value of sinusoidal wave}$$

$$= (0.695 + 0.62m \sin \omega t) V$$

$$\therefore I_D = I_D + i_d$$

$$= (9.16m + \frac{0.62}{5.92} \sin \omega t) A$$

3a)

ON $i_D > 0$
OFF $V_D < 0$ 

① Firstly, assume both diodes are conducting, node a will have a voltage drop of 0.75V, node b = 0V

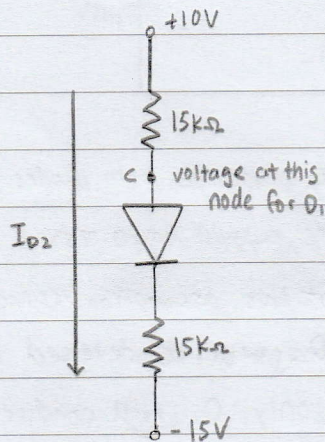
② By the first assumption, a voltage drop of 15V across 15kΩ resistor and a current of 1mA will flow down.

③ For both diode to be conducting, current flowing from top 15kΩ have to be greater than 1mA

$$I_{15k\Omega} = \frac{9.25V}{15k\Omega}$$

$$= 0.617 \text{ mA} < 1 \text{ mA}$$

∴ current will have to flow from ground as a supplementary current to satisfy the bigger current
 ↳ D_1 will be reversed biased (not conducting o/c)
 ↳ only D_2 conducts

Q-pt for D_2

$$(I_{D2}, V_{D2})$$

$$= \left(\frac{10 - (-15) - 0.75}{15k\Omega + 15k\Omega}, 0.75V \right)$$

$$= (0.808 \text{ mA}, 0.75V)$$

Q-pt for D_1

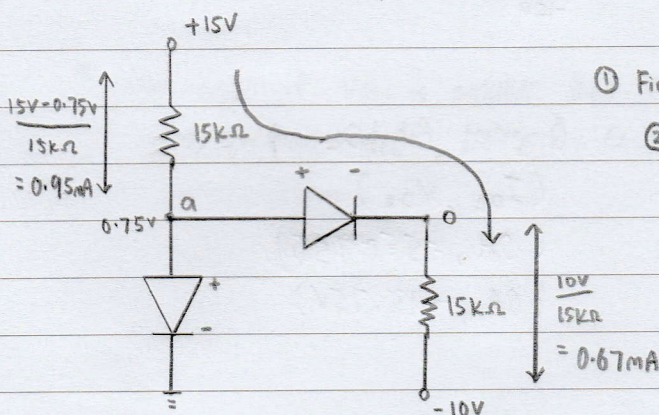
$$(I_{D1}, V_{D1})$$

$$= (0A, 10V - 0.808 \text{ mA} (15k\Omega))$$

$$= (0A, -2.125V)$$

$$= (0A, -2.13V)$$

b)



① First, assume node a = 0.75V

② current flowing from top 15kΩ resistor is greater than bottom, $0.95 \text{ mA} > 0.67 \text{ mA}$
 ∴ able to flow through both diode
 ↳ D_1 and D_2 conducting

Q-pt for D_2

$$(I_{D2}, V_{D2})$$

$$= (0.67 \text{ mA}, 0.75V)$$

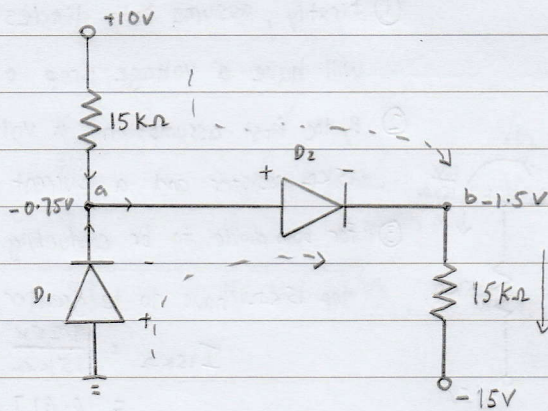
Q-pt for D_1

$$(I_{D1}, V_{D1})$$

$$= (0.95 \text{ mA} - 0.67 \text{ mA}, 0.75V)$$

$$= (0.28 \text{ mA}, 0.75V)$$

c)



① Firstly, assume both diodes are conducting
node $a = 0.75V$

same as part (a), current will have to flow from ground to satisfy the bigger current

$$\therefore \text{node } a = -0.75V$$

$$\text{node } b = -1.5V$$

Both D_1 and D_2 are conducting

Q-pt for D_1

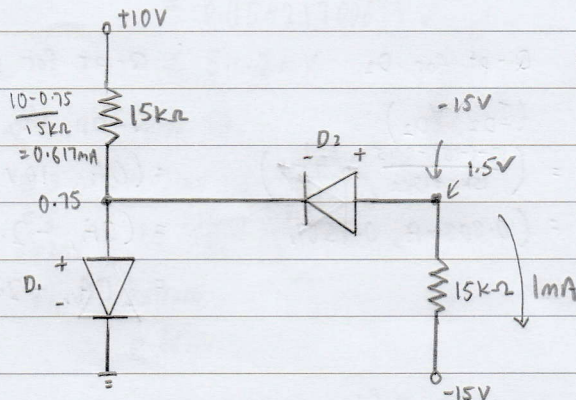
$$= (0.9mA - \frac{10.75}{15k\Omega}, 0.75V)$$

$$= (0.183mA, 0.75V)$$

Q-pt for D_2

$$= (0.9mA, 0.75V)$$

d)



① Firstly, assume both diodes are conducting
node a will be $0.75V$

But this assumption cannot work as D_2 will be reversed biased
only D_1 will conduct

Q-point for D_1

$$(I_{D1}, V_{D1})$$

$$(0.617mA, 0.75V)$$

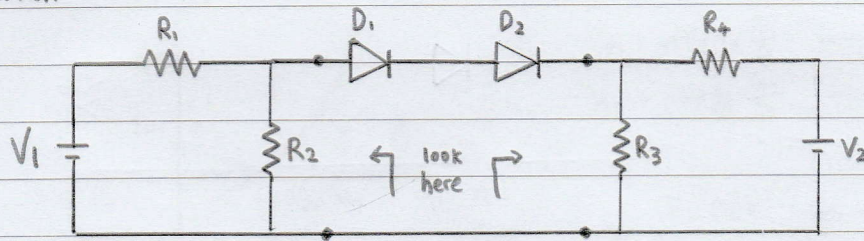
Q-point for D_2

$$(I_{D2}, V_{D2})$$

$$(0A, -15 - 0.75V)$$

$$(0A, -15.75V)$$

Extra question



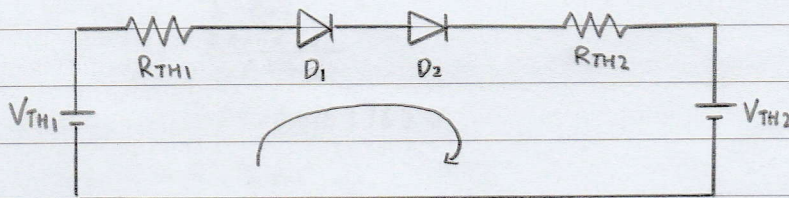
By Thevenin Theorem

$$V_{TH1} = \frac{R_2}{R_1 + R_2} V_1$$

$$R_{TH1} = R_1 // R_2$$

$$V_{TH2} = \frac{R_3}{R_3 + R_4} V_2$$

$$R_{TH2} = R_3 // R_4$$



Empirical Diode Junction Equation

$$V_D = nV_T \ln \left(\frac{I_D}{I_S} \right) \quad \text{--- (1)}$$

Load line equation

$$I_D = \frac{V_{TH1} - V_{TH2} - 2V_D}{R_{TH1} + R_{TH2}} \quad \text{--- (2)}$$

use this 2 equation
and do iteration method
to solve Q-point

Q-pt same for both

* What happen if V_{TH1} is smaller than V_{TH2}
→ question ended, current = 0